

SKiiP 11NAB065V1



MiniSKiiP® 1

3-phase bridge rectifier +
brake chopper + 3-phase
bridge inverter
SKiiP 11NAB065V1

Features

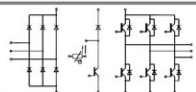
- Ultrafast NPT IGBTs
- Robust and soft freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognised file no. E63532

Typical Applications*

- Inverter up to 3,5 kVA
- Typical motor power 1,5 kW

Remarks

- V_{CEsat} , V_F = chip level value



NAB

Absolute Maximum Ratings		$T_B = 25^\circ\text{C}$, unless otherwise specified	
Symbol	Conditions	Values	Units
IGBT - Inverter, Chopper			
V_{CES}		600	V
I_C	$T_B = 25 (70)^\circ\text{C}$	12 (10)	A
I_{CRM}		12	A
V_{GES}		± 20	V
T_J		-40 ... +150	$^\circ\text{C}$
Diode - Inverter, Chopper			
I_F	$T_B = 25 (70)^\circ\text{C}$	12 (12)	A
I_{FRM}		12	A
T_J		-40 ... +150	$^\circ\text{C}$
Diode - Rectifier			
V_{RRM}		800	V
I_F	$T_B = 70^\circ\text{C}$	35	A
I_{FSM}	$t_p = 10 \text{ ms, sin } 180^\circ, T_J = 25^\circ\text{C}$	220	A
i^2t	$t_p = 10 \text{ ms, sin } 180^\circ, T_J = 25^\circ\text{C}$	240	A^2s
T_J		-40 ... +150	$^\circ\text{C}$
Module			
I_{RMS}	per power terminal (20 A / spring)	20	A
T_{stg}		-40 ... +125	$^\circ\text{C}$
V_{Isol}	AC, 1 min.	2500	V

Characteristics		$T_B = 25^\circ\text{C}$, unless otherwise specified			
Symbol	Conditions	min.	typ.	max.	Units
IGBT - Inverter, Chopper					
V_{CEsat}	$I_{Cnom} = 6 \text{ A}, T_J = 25 (125)^\circ\text{C}$ $V_{GE} = V_{CE}, I_C = 0,5 \text{ mA}$	3	2 (2,2) 4	2,5 (2,7) 5	V
$V_{CE(TH)}$	$T_J = 25 (125)^\circ\text{C}$		1,2 (1,1)	1,3 (1,2)	V
$V_{CE(TO)}$	$T_J = 25 (125)^\circ\text{C}$		133 (183)	200 (250)	m Ω
r_T	$T_J = 25 (125)^\circ\text{C}$				m Ω
C_{iss}	$V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$		0,32		nF
C_{oss}	$V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$		0,08		nF
C_{res}	$V_{CE} = 25 \text{ V}, V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$		0,03		nF
$R_{\theta(j-c)}$	per IGBT		1,9		K/W
$t_{i(on)}$	under following conditions		25		ns
t_r	$V_{CC} = 300 \text{ V}, V_{CE} = \pm 15 \text{ V}$		30		ns
$t_{i(off)}$	$I_{Cnom} = 6 \text{ A}, T_J = 125^\circ\text{C}$		195		ns
t_f	$R_{con} = R_{coff} = 120 \Omega$		20		ns
E_{on}	inductive load		0,3		mJ
E_{off}			0,2		mJ
Diode - Inverter, Chopper					
$V_F = V_{EC}$	$I_{Fnom} = 6 \text{ A}, T_J = 25 (125)^\circ\text{C}$		1,3 (1,2)	1,5 (1,4)	V
$V_{(TO)}$	$T_J = 25 (125)^\circ\text{C}$		1 (0,9)	1,1 (1)	V
r_T	$T_J = 25 (125)^\circ\text{C}$		45 (50)	60 (70)	m Ω
$R_{\theta(j-c)}$	per diode		2,5		K/W
I_{FRM}	under following conditions		8,3		A
C_{rr}	$I_{Fnom} = 6 \text{ A}, V_R = 300 \text{ V}$		0,6		μC
E_{rr}	$V_{GE} = 0 \text{ V}, T_J = 125^\circ\text{C}$		0,2		mJ
	$di_F/dt = 430 \text{ A}/\mu\text{s}$				
Diode - Rectifier					
V_F	$I_{Fnom} = 15 \text{ A}, T_J = 25^\circ\text{C}$		1,1		V
$V_{(TO)}$	$T_J = 150^\circ\text{C}$		0,8		V
r_T	$T_J = 150^\circ\text{C}$		20		m Ω
$R_{\theta(j-c)}$	per diode		1,5		K/W
Temperature Sensor					
R_{ts}	3 %, $T_r = 25 (100)^\circ\text{C}$		1000(1670)		Ω
Mechanical Data					
w			35		g
M_b	Mounting torque		2	2,5	Nm

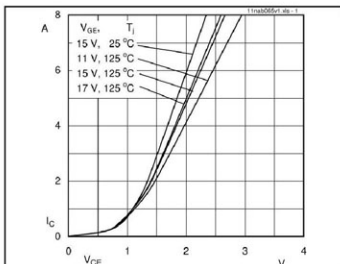


Fig. 1 Typ. output characteristic

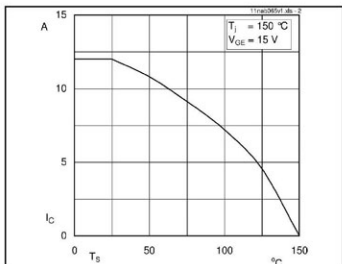


Fig. 2 Typ. rated current vs. temperature

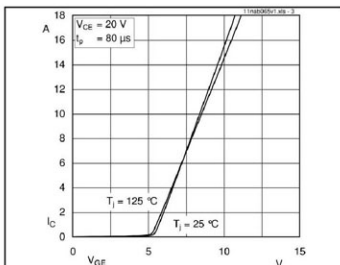


Fig. 3 Typ. transfer characteristic

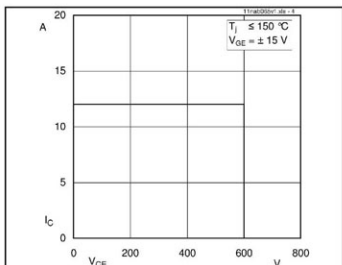


Fig. 4 Reverse bias safe operating area

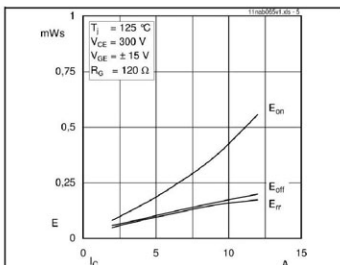


Fig. 5 Typ. Turn-on / off energy = $f(I_c)$

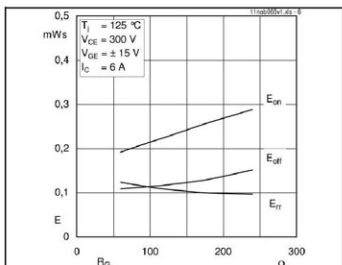


Fig. 6 Typ. Turn-on / off energy = $f(R_c)$

